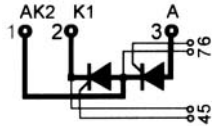


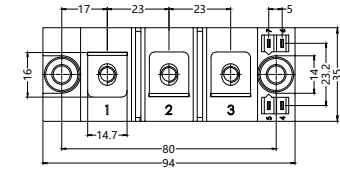
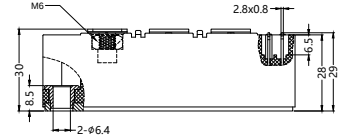
STT130GKXXB

Thyristor-Thyristor Modules



Type	V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V
STT130GK08B	900	800
STT130GK12B	1300	1200
STT130GK14B	1500	1400
STT130GK16B	1700	1600
STT130GK18B	1900	1800

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS} , I_{FRMS} I_{TAVM} , I_{FAVM}	$T_V = T_{VJM}$ $T_C = 85^{\circ}C$; 180° sine	300 130	A
I_{TSM} , I_{FSM}	$T_V = 45^{\circ}C$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	5500 5850	A
	$T_V = T_{VJM}$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	4800 5100	
$\int i^2 dt$	$T_V = 45^{\circ}C$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	151000 142000	A^2s
	$T_V = T_{VJM}$ $V_R = 0$ $t = 10ms$ (50Hz), sine $t = 8.3ms$ (60Hz), sine	115000 108000	
$(di/dt)_{cr}$	$T_V = T_{VJM}$ $f = 50Hz$, $t_p = 200\mu s$ $V_D = 2/3 V_{DRM}$ $I_G = 0.5A$ $di/dt = 0.5A/\mu s$ repetitive, $I_T = 500A$	150	A/ μs
	non repetitive, $I_T = 500A$	500	
$(dv/dt)_{cr}$	$T_V = T_{VJM}$; $V_{DR} = 2/3 V_{DRM}$ $R_{GK} = \infty$; method 1 (linear voltage rise)	1000	V/ μs
P_{GM}	$T_V = T_{VJM}$ $I_T = I_{TAVM}$ $t_p = 30\mu s$ $t_p = 500\mu s$	120 60	W
P_{GAV}		8	W
V_{RGM}		10	V
T_V T_{VJM} T_{stg}		-40...+125 125 -40...+125	$^{\circ}C$
V_{ISOL}	50/60Hz, RMS $I_{ISOL} \leq 1mA$ $t = 1min$ $t = 1s$	3000 3600	V~
M_d	Mounting torque (M6) Terminal connection torque (M6)	2.25-2.75/20-25 4.5-5.5/40-48	Nm/lb.in.
Weight	Typical	173	g

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STT130GKXXB

Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	10	mA
V_T, V_F	$I_T, I_F=390A; T_{VJ}=25^{\circ}C$	1.56	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^{\circ}C$)	0.8	V
r_T		1.5	mΩ
V_{GT}	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	2.5 2.6	V
I_{GT}	$V_D=6V; T_{VJ}=25^{\circ}C$ $T_{VJ}=-40^{\circ}C$	150 200	mA
V_{GD}	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2	V
I_{GD}		10	mA
I_L	$T_{VJ}=25^{\circ}C; t_p=30\mu s; V_D=6V$ $I_G=0.5A; di_G/dt=0.5A/\mu s$	300	mA
I_H	$T_{VJ}=25^{\circ}C; V_D=6V; R_{GK}=\infty$	200	mA
t_{gd}	$T_{VJ}=25^{\circ}C; V_D=1/2V_{DRM}$ $I_G=0.5A; di_G/dt=0.5A/\mu s$	2	us
t_q	$T_{VJ}=T_{VJM}; I_T=160A; t_p=200\mu s; -di/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$ typ.	150	us
Q_s	$T_{VJ}=T_{VJM}; I_T, I_F=300A; -di/dt=50A/\mu s$	550	uC
I_{RM}		235	A
R_{thJC}	per thyristor/diode; DC current per module	0.23 0.115	K/W
R_{thJK}	per thyristor/diode; DC current per module	0.33 0.165	K/W
d_s	Creeping distance on surface	12.7	mm
d_A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s ²

FEATURES

- * International standard package
- * Copper base plate
- * Glass passivated chips
- * Isolation voltage 3600 V~
- * UL file NO.E310749
- * RoHS compliant

APPLICATIONS

- * Motor control
- * Power converter
- * Heat and temperature control for industrial furnaces and chemical processes
- * Lighting control
- * Contactless switches

ADVANTAGES

- * Space and weight savings
- * Simple mounting
- * Improved temperature and power cycling
- * Reduced protection circuits



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Thyristor-Thyristor Modules

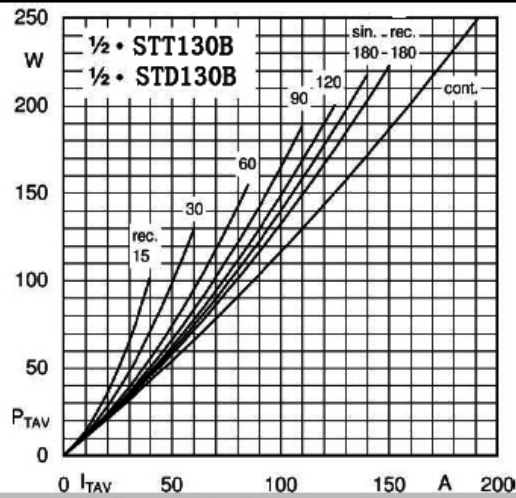


Fig. 1L Power dissipation per thyristor vs. on-state current

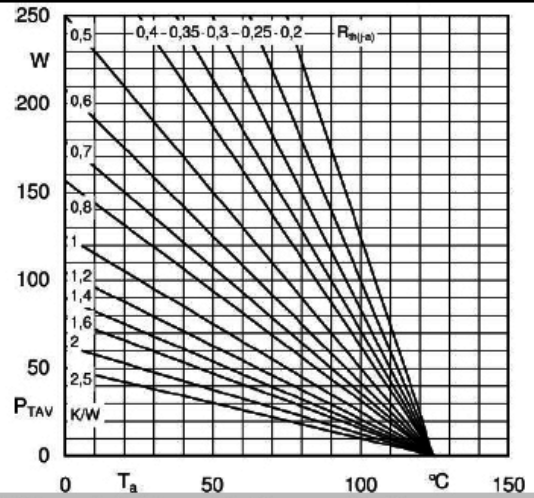


Fig. 1R Power dissipation per thyristor vs. ambient temp.

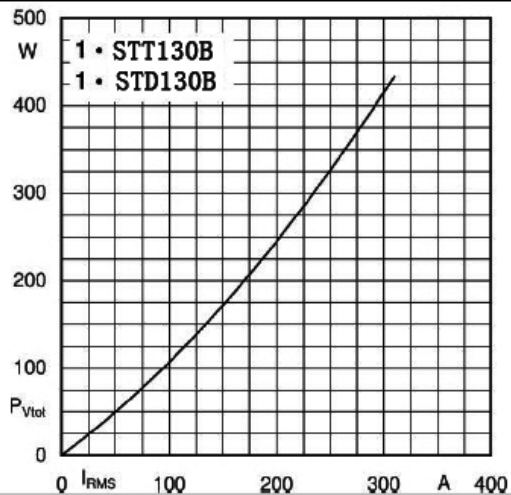


Fig. 2L Power dissipation per module vs. rms current

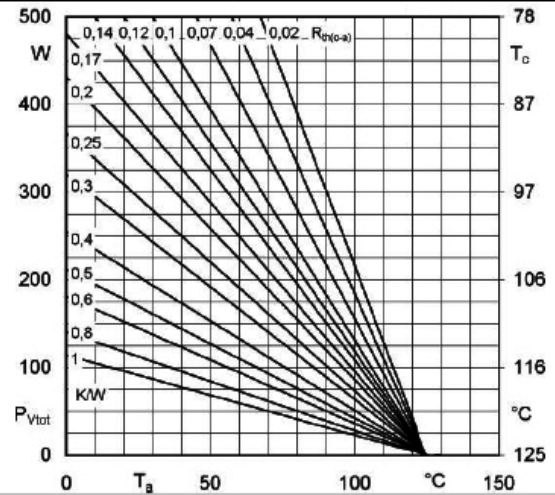


Fig. 2R Power dissipation per module vs. case temp.

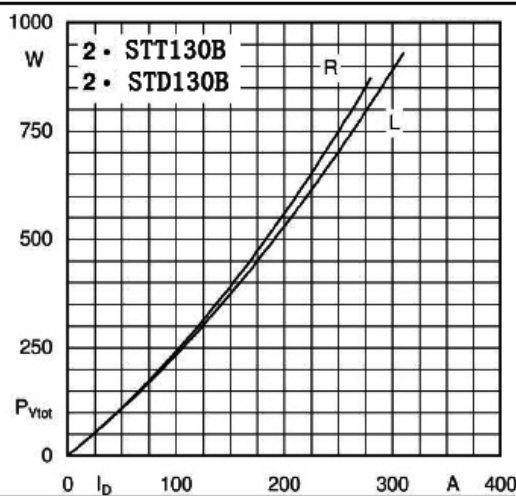


Fig. 3L Power dissipation of two modules vs. direct current

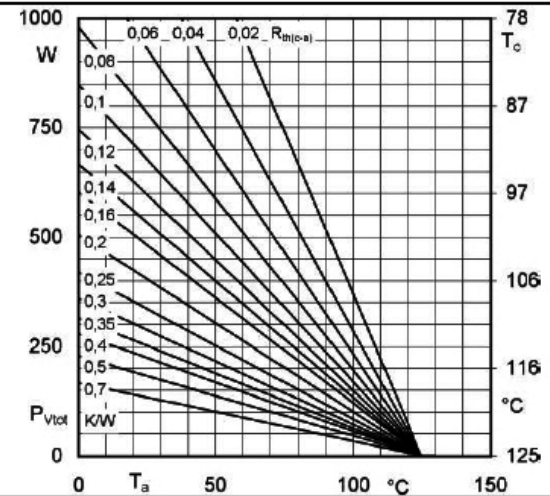


Fig. 3R Power dissipation of two modules vs. case temp.

STT130GKXXB

Thyristor-Thyristor Modules

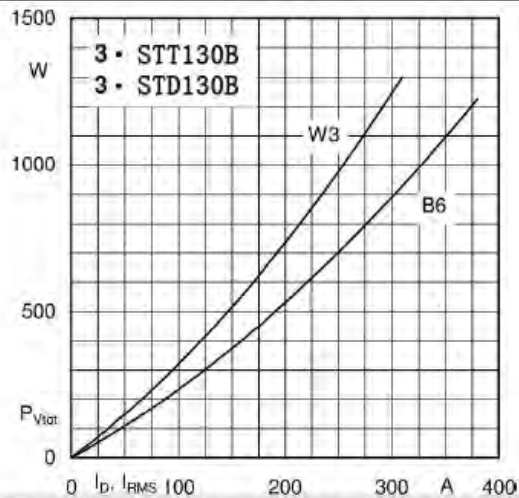


Fig. 4L Power dissipation of three modules vs. direct and rms current

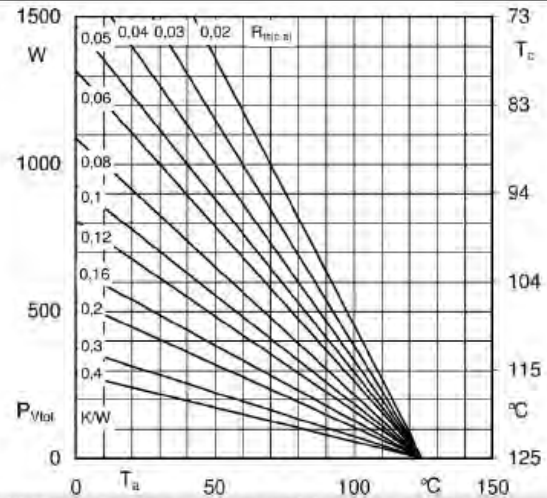


Fig. 4R Power dissipation of three modules vs. case temp.

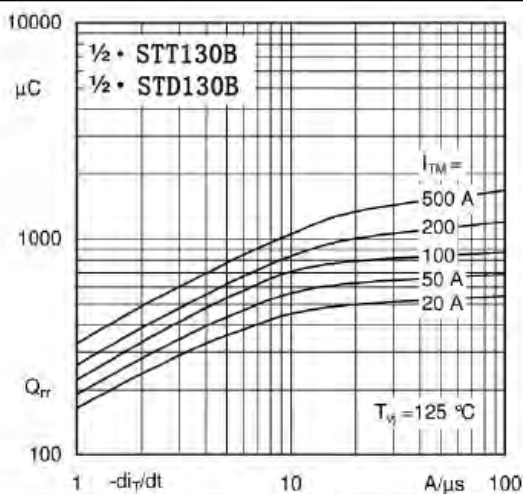


Fig. 5 Recovered charge vs. current decrease

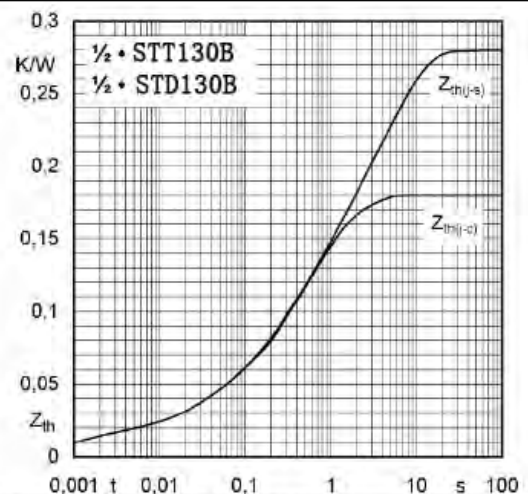


Fig. 6 Transient thermal impedance vs. time

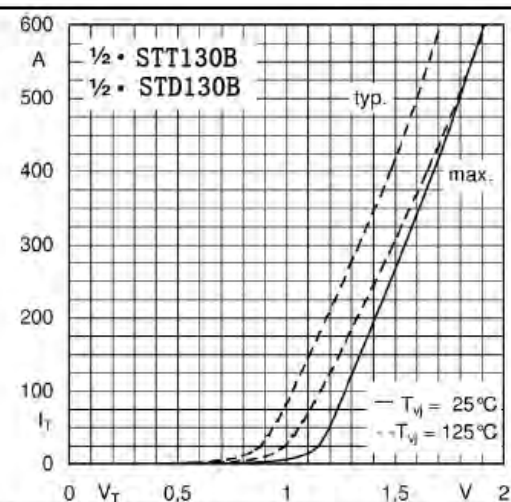


Fig. 7 On-state characteristics

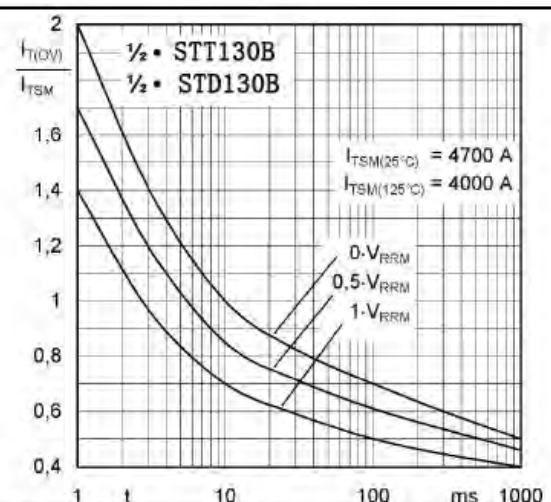


Fig. 8 Surge overload current vs. time